

DR-40

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|--|---|
| 1. Color | Infrared |
| 2. Material | AlGaAs |
| 3. Electrode | N side (cathode): Au / P side (anode): Au |
| 4. Electrode pattern | (Fig.) |
| 5. Chip size | 0.375mm × 0.375mm × 0.260mmH (Fig.) |
| 6. Electro-Optical characteristics (Ta = 25°C) | |

Parameters	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Power*	Po	IF = 20mA	1.0	1.6		mW
Forward Voltage	VF	IF = 20mA		1.30	1.50	V
Reverse Current	IR	VR = 5V			10	μA
Peak Wavelength	λP	IF = 20mA		880		nm
Spectral Radiation Bandwidth	Δλ	IF = 20mA		80		nm

* Power Measurement at RESONAC PHOTONICS.

LED chip : To be mounted on TO-18 gold header without resin coating.

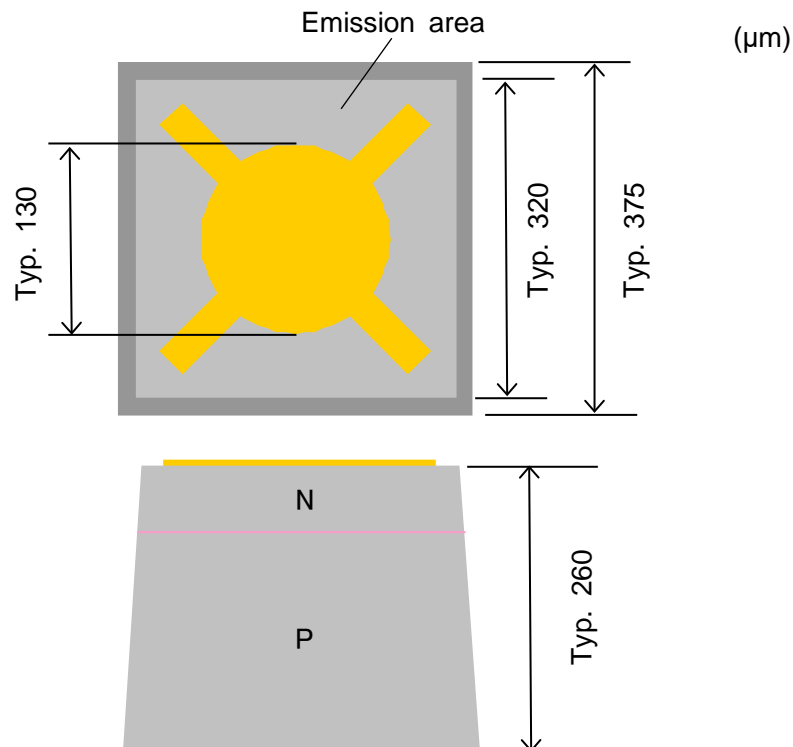


Fig. Electrode pattern & Chip size

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